Diode Semiconductor Device - Page 1 of 1



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Inclosure Material: Glass **Overall Length:** 0.170 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.076 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 20.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 0.10 microamperes forward current, average peak **Power Rating Per Characteristic:** 250.0 milliwatts small-signal input power, common-collector preset Maximum Operating Tempurature Per Measurement Point: 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a Unit Of Measure: --**Demilitarization:** No Fiig: A110a0